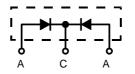


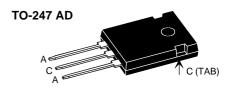
# HiPerFRED™ Epitaxial Diode with common cathode and soft recovery

## **Preliminary Data**

| V <sub>RSM</sub> | V <sub>RRM</sub> | Туре        |  |  |
|------------------|------------------|-------------|--|--|
| 200              | 200              | DSEC 30-02A |  |  |



 $I_{FAV} = 2x 15 A$   $V_{RRM} = 200 V$  $t_{rr} = 30 ns$ 



A = Anode, C = Cathode, TAB = Cathode

| Symbol  | Test Conditions  | Maximum Ratings           |                |  |
|---|--|---------------------------|----------------|--|
| I <sub>FRMS</sub>                                 | T <sub>c</sub> = 150°C; rectangular, d = 0.5                               | 50<br>15                  | A<br>A         |  |
| I <sub>FSM</sub>                                  | $T_{VJ} = 45^{\circ}C$ ; $t_p = 10$ ms (50 Hz), sine                       | 140                       | A              |  |
| E <sub>AS</sub>                                   | $T_{VJ}$ = 25°C; non-repetitive<br>$I_{AS}$ = 2.5 A; L = 180 $\mu$ H       | 0.8                       | mJ             |  |
| I <sub>AR</sub>                                   | $V_A = 1.5 \cdot V_R \text{ typ.}; f = 10 \text{ kHz}; \text{ repetitive}$ | 0.3                       | Α              |  |
| T <sub>VJ</sub> T <sub>VJM</sub> T <sub>stg</sub> |  | -55+175<br>175<br>-55+150 | °C<br>°C<br>°C |  |
| P <sub>tot</sub>                                  | T <sub>C</sub> = 25°C  | 95                        | W              |  |
| M <sub>d</sub>                                    | mounting torque  | 0.450.55<br>45            | Nm<br>lb.in.   |  |
| Weight  | typical  | 6                         | g              |  |

| Symbol            | Test Conditions  | Characteristic Values |              |            |
|-------------------|--|-----------------------|--------------|------------|
|                   |  | typ.                  | max.         |            |
| I <sub>R</sub> ①  | $T_{VJ} = 25^{\circ}C$ $V_R = V_{RRM}$<br>$T_{VJ} = 150^{\circ}C$ $V_R = V_{RRM}$                                    |                       | 100<br>0.5   | μA<br>mA   |
| V <sub>F</sub> ②  | $I_F = 15 \text{ A};$ $T_{VJ} = 150^{\circ}\text{C}$<br>$T_{VJ} = 25^{\circ}\text{C}$                                |                       | 0.85<br>1.05 | V          |
| R <sub>thJC</sub> |  | 0.25                  | 1.6          | K/W<br>K/W |
| t <sub>rr</sub>   | $I_F = 1 \text{ A}$ ; -di/dt = 100 A/ $\mu$ s;<br>$V_R = 30 \text{ V}$ ; $T_{VJ} = 25^{\circ}\text{C}$               | 25                    |              | ns         |
| I <sub>RM</sub>   | $V_R = 100 \text{ V}; \ I_F = 25 \text{ A}; -di_F/dt = 100 \text{ A}/\mu\text{s}$<br>$T_{VJ} = 100 ^{\circ}\text{C}$ | 3.5                   | 4.4          | А          |

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %

@ Pulse Width = 300  $\mu s,$  Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, test conditions and dimensions.

#### **Features**

- · International standard package
- · Planar passivated chips
- · Very short recovery time
- Extremely low switching losses
- Low I<sub>RM</sub>-values
- · Soft recovery behaviour
- Epoxy meets UL 94V-0

#### **Applications**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### **Advantages**

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I<sub>RM</sub> reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Dimensions see outlines.pdf